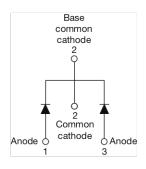


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Ultrafast Rectifier, 2 x 8 A FRED Pt®





| PRIMARY CHARACTERISTICS | | | | | | |
|----------------------------------|--------------------|--|--|--|--|--|
| Package | 3L TO-220AB | | | | | |
| I _{F(AV)} | 2 x 8 A | | | | | |
| V _R | 200 V | | | | | |
| V _F at I _F | 0.895 V | | | | | |
| t _{rr} typ. | See Recovery table | | | | | |
| T _J max. | 175 °C | | | | | |
| Circuit configuration | Common cathode | | | | | |

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current



- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

VS-MUR1620CT-M3 is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | |
|---|--------------|-----------------------------------|---|-------------|-------|--|--|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | MAX. | UNITS | | | | |
| Peak repetitive reverse voltage | | V_{RRM} | | 200 | V | | | | |
| per leg | | | | 8.0 | | | | | |
| Average rectified forward current | total device | I _{F(AV)} | Rated V _R , T _C = 150 °C | 16 | A | | | | |
| Non-repetitive peak surge current per leg | | I _{FSM} | | 100 | _ ^ | | | | |
| Peak repetitive forward current per | leg | I _{FM} | Rated V _R , square wave, 20 kHz, T _C = 150 °C | 16 | | | | | |
| Operating junction and storage tem | peratures | T _J , T _{Stg} | | -65 to +175 | °C | | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | | | |
|--|--|---|-----|-----|-------|----|--|--|--|
| PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. | | | | | | | | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | Ι _R = 100 μΑ | 200 | - | - | ., | | | |
| Converd veltage | V _F | I _F = 8 A | - | - | 0.975 | V | | | |
| Forward voltage | | I _F = 8 A, T _J = 150 °C | - | - | 0.895 | | | | |
| Povorco logicado ourrent | | $V_R = V_R$ rated | - | - | 5 | | | | |
| Reverse leakage current | I _R | $T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$ | - | - | 250 | μΑ | | | |
| Junction capacitance | Junction capacitance C_T $V_R = 200 \text{ V}$ | | - | 25 | - | pF | | | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8.0 | - | nH | | | |



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| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | | | |
|---|-----------------|--|--|------|------|------|---------|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| | | I _F = 1.0 A, dI _F /dt = | 50 A/μs, V _R = 30 V | - | - | 35 | | | |
| Povorco rocovory timo | | $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{REC} = 0.25 \text{ A}$ | | - | - | 25 | no | | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 20 | - | ns A | | |
| | | T _J = 125 °C | | - | 34 | - | | | |
| Pools recovery ourrent | | T _J = 25 °C | I _F = 8 A dI _F /dt = 200 A/μs | - | 1.7 | - | | | |
| Peak recovery current | IRRM | T _J = 125 °C | V _R = 160 V | - | 4.2 | - | | | |
| Reverse recovery charge | 0 | T _J = 25 °C | | - | 23 | - | nC | | |
| | Q _{rr} | T _J = 125 °C | | - | 75 | - | l IIC | | |

| THERMAL MECHANICAL SPECIFICATIONS | | | | | | | | | | |
|---|-----------------------------------|--|--------------|------|------------|------------------------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C | | | | |
| Thermal resistance, junction to case per leg | R _{thJC} | | - | - | 3.0 | | | | | |
| Thermal resistance, junction to ambient per leg | R _{thJA} | | - | - | 50 | °C/W | | | | |
| Thermal resistance, case to heatsink | R _{thCS} | Mounting surface, flat, smooth and greased | - | 0.5 | - | | | | | |
| Moight | | | - | 2.0 | - | g | | | | |
| Weight | | | - | 0.07 | - | oz. | | | | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | | | | |
| Marking device | | Case style 3L TO-220AB | | MUR1 | 620CT | | | | | |

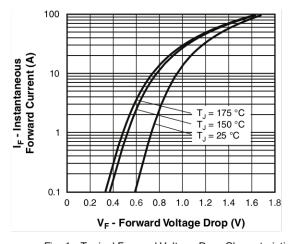


Fig. 1 - Typical Forward Voltage Drop Characteristics

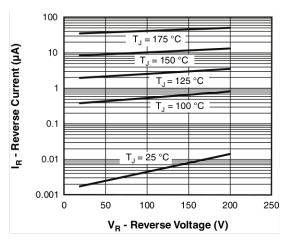


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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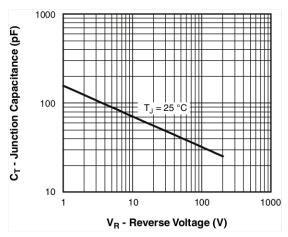


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

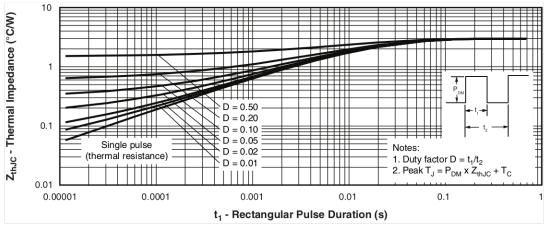


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

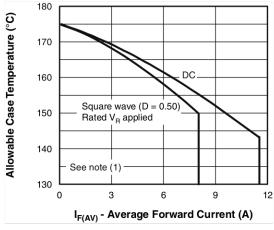


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

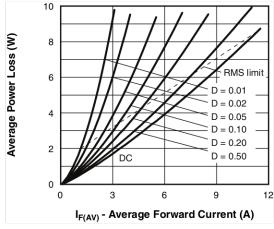


Fig. 6 - Forward Power Loss Characteristics



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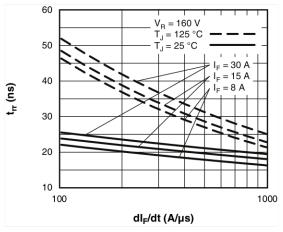


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

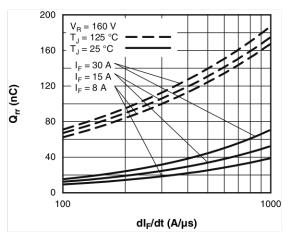


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{B1} \times I_B (1 - D)$; I_B at $V_{B1} = rated V_B$

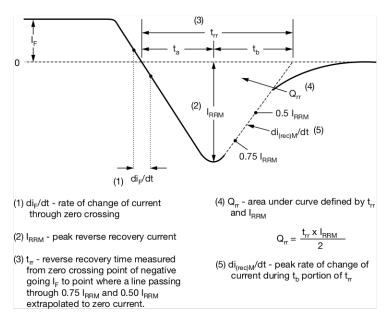
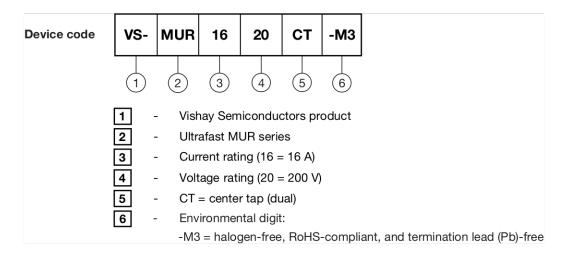


Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE



| ORDERING INFORMATION (Example) | | | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | |
| VS-MUR1620CT-M3 | 50 | 1000 | Antistatic plastic tube | | | | | |

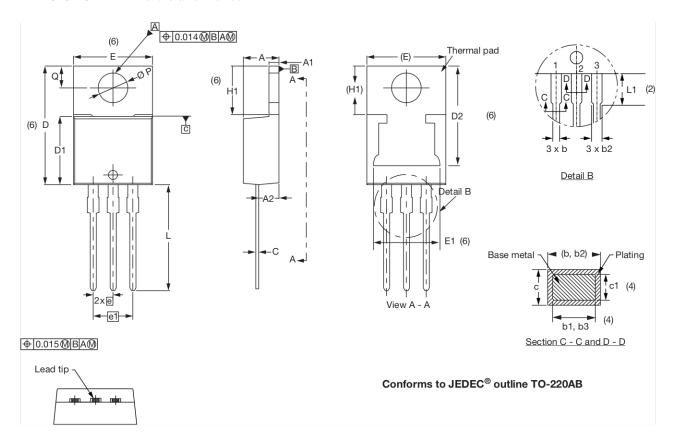
| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|--------------------------|--|--|--|--|--|
| Dimensions | www.vishay.com/doc?96154 | | | | | |
| Part marking information | www.vishay.com/doc?95028 | | | | | |



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3L TO-220AB

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIN | IETERS | INC | HES | NOTES | SYMBOL | MILLIM | IETERS | | | |
|----------|--------|--------|-------|-------|-------|--------|--------|----------|------|------|--|
| STIVIDOL | MIN. | MAX. | MIN. | MAX. | NOTES | NOTES | NOTES | STIVIBOL | MIN. | MAX. | |
| Α | 4.25 | 4.65 | 0.167 | 0.183 | | D2 | 11.68 | 13.30 | | | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | | E | 10.11 | 10.51 | | | |
| A2 | 2.50 | 2.92 | 0.098 | 0.115 | | E1 | 6.86 | 8.89 | | | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | | е | 2.41 | 2.67 | | | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 | e1 | 4.88 | 5.28 | | | |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | | H1 | 6.09 | 6.48 | | | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | L | 13.52 | 14.02 | | | |
| С | 0.36 | 0.61 | 0.014 | 0.024 | | L1 | 3.32 | 3.82 | | | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 | ØΡ | 3.54 | 3.91 | | | |
| D | 14.85 | 15.35 | 0.585 | 0.604 | 3 | Q | 2.60 | 3.00 | | | |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | | | | | | | |

| SYMBOL | MILLIN | IETERS | INC | NOTES | |
|---------|--------|--------|-------|-------|-------|
| STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D2 | 11.68 | 13.30 | 0.460 | 0.524 | 6, 7 |
| Е | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6 |
| L | 13.52 | 14.02 | 0.532 | 0.552 | |
| L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| ØР | 3.54 | 3.91 | 0.139 | 0.154 | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| | | | | | |

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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